

Correction to: Microwave Oscillators and Detectors Based on Magnetic Tunnel Junctions



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The original version of the book was published without incorporating the chapter “Microwave Oscillators and Detectors Based on Magnetic Tunnel Junctions” corrections provided by the corresponding author. The correction chapter and book have been updated with the changes.

The updated version of this chapter can be found at https://doi.org/10.1007/978-981-15-6912-8_1

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